



## SAM<sup>TM</sup> Data Sheet SAM-2150-8-10ps-x, $\lambda$ = 2150 nm

 $\lambda = 2150 \text{ nm}$ Laser wavelength

High reflection band  $\lambda = 2050 ... 2200 \text{ nm}$ 

Absorbance  $A_0 = 8 \%$  $\Delta R = 5 \%$ Modulation depth Non-saturable loss  $A_{ns} = 3 \%$ 

Saturation fluence  $\Phi_{\text{sat}} = 80 \, \mu \text{J/cm}^2$ 

Relaxation time constant  $\tau \sim 10 \text{ ps}$ 

 $\Phi = 2 \text{ mJ/cm}^2$ Damage threshold

4.0 mm x 4.0 mm; other dimensions on request Chip area

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

 $\mathbf{x} = 0$ unmounted glued on a gold plated Cu-cylinder with 12.7 mm  $\varnothing$ x = 12.7 gx = 25.4 gglued on a gold plated Cu-cylinder with 25.4 mm Ø soldered on a gold plated Cu-cylinder with 12.7 mm  $\varnothing$ x = 12.7 ssoldered on a gold plated Cu-cylinder with 25.4 mm  $\varnothing$ x = 25.4 smounted on a 1 m monomode fiber cable with FC connector  $\mathbf{x} = \mathbf{FC}$ 

## Low intensity spectral reflectance

